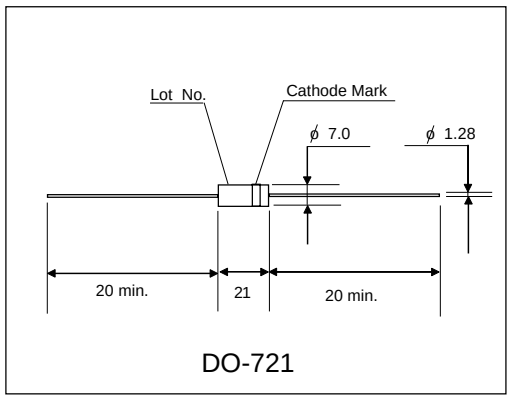
HVGT

ESJC13-09

450mA 9kV HIGH VOLTAGE DIODES

Finds use in applications such as Monitors, Static electricity dust collectors,Laser power supplies,ect..

■ Outline Drawings : mm



DO-721

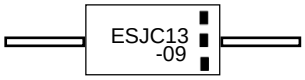
■ Features

- High speed switching
- High Current
- High surge resisitivity for CRT discharge
- High reliability design
- High Voltage

■ Applications

- X light Power supply
- Laser
- Voltage doubler circuit
- Microwave emission power

■ Cathode Mark

Type	Mark
ESJC13-09	

■ Maximum Ratings and Characteristics

● Absolute Maximum Ratings

Items	Symbols	Condition	ESJC13-09	Units
Repetitive Peak Renerse Voltage	V_{RRM}		9.0	kV
Average Output Current	I_O	Ta=25°C,Resistive Load	450	mA
Suege Current	I_{FSM}		30	A_{peak}
Junction Temperature	Tj		125	°C
Allowable Operation Case Temperature	Tc		125	°C
Storage Temperature	T_{stg}		-40 to +130	°C

● Electrical Characteristics (Ta=25°C Unless otherwise specified)

Items	Symbols	Conditions	ESJC13-09	Units
Maximum Forward Voltage Drop	V_F	at 25°C,I_F =$I_{F(AV)}$	9.0	V
Maximum Reverse Current	IR1	at 25°C,V_R =V_{RRM}	5.0	uA
	IR2	at 100°C,V_R =V_{RRM}	50	uA
Maximum Reverse Recovery Time	Trr	at 25°C	--	nS
Junction Capacitance	Cj	at 25°C,V_R=0V,f=1MHz	--	pF

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Http://www.getedz.com E-mail:sales@getedz.com